



LSF0204x 适用于漏极开路 and 推挽应用的 4 位双向多电压电平转换器

1 特性

- 用无方向端子提供双向电压转换
- 最大传播延迟少于 1.5ns
- 支持高速转换，大于 100MHz
- 支持 I_{off} ，局部断电模式（请参见 [Feature Description](#)）
- 可实现以下电压之间的双向电压电平转换
 - 1.0V ↔ 1.8/2.5/3.3/5V
 - 1.2V ↔ 1.8/2.5/3.3/5V
 - 1.8V ↔ 2.5/3.3/5V
 - 2.5V ↔ 3.3/5V
 - 3.3V ↔ 5V
- 低待机电流
- 支持 TTL 的 5V 耐受 I/O 端口
- 低导通电阻 R_{on} 提供较少的信号失真
- 针对 EN 为低电平的高阻抗 I/O 端子
- 直通引脚分配以简化印刷电路板 (PCB) 走线路由
- 锁断性能超过 100mA，符合 JESD17 规范
- -40°C 至 125°C 工作温度范围
- 静电放电 (ESD) 性能测试符合 JESD 22 规范
 - 2000V 人体模型 (A114-B, II 类)
 - 200V 机器模型 (A115-A)
 - 1000V 充电器件模型 (C101)

2 应用

- GPIO, MDIO, PMBus, SMBus, SDIO, UART, I²C, 和其他电信基础设施中的接口
- 工业用
- 汽车用
- 个人计算

3 说明

LSF 系列是工作电压介于 1.0V 至 4.5V (V_{ref_A}) 和 1.8V 至 5.5V (V_{ref_B}) 之间的双向电压电平转换器。此器件在无需方向端子的条件下便可在开漏或推挽应用中实现 1.0V 至 5.0V 的双向电压转换。对于采用 15pF 电容器和 165Ω 上拉电阻器的开漏系统，LSF 系列支持传输速度大于 100MHz 电平转换应用。

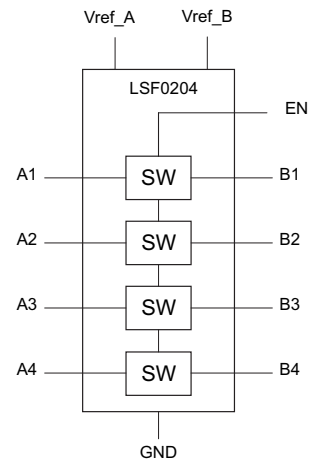
当 An 或 Bn 端口为低电平时，此开关处于接通状态，并且在 An 和 Bn 端口之间存在一个低电阻连接。开关的低 R_{on} 可用最小传播延迟和信号失真来实现连接。A 端或 B 端的电压将限制为 V_{ref_A} ，且可上拉至 V_{ref_A} 到 5V 之间的任何电压水平。利用此功能，可在无需方向控制的情况下实现用户选择的较高和较低电压间的无缝转换。

器件信息⁽¹⁾

器件型号	封装	封装尺寸 (标称值)
LSF0204x	薄型小外形尺寸封装 (TSSOP) (14)	5.00mm x 4.40mm
	UQFN (12)	2.00mm x 1.70mm
	VQFN (14)	3.50mm x 3.50mm
	DSBGA (12)	1.90mm x 1.40mm

(1) 要了解所有可用封装，请见数据表末尾的可订购产品附录。

简化电路原理图



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4 修订历史记录

Changes from Original (November 2014) to Revision A

Page

• 从首页产品预览更改为完整数据表	1
• 已将说明中的文本从“传输速度大于 100Mbps”改为“传输速度大于 100MHz”	1

5 Description (Continued)

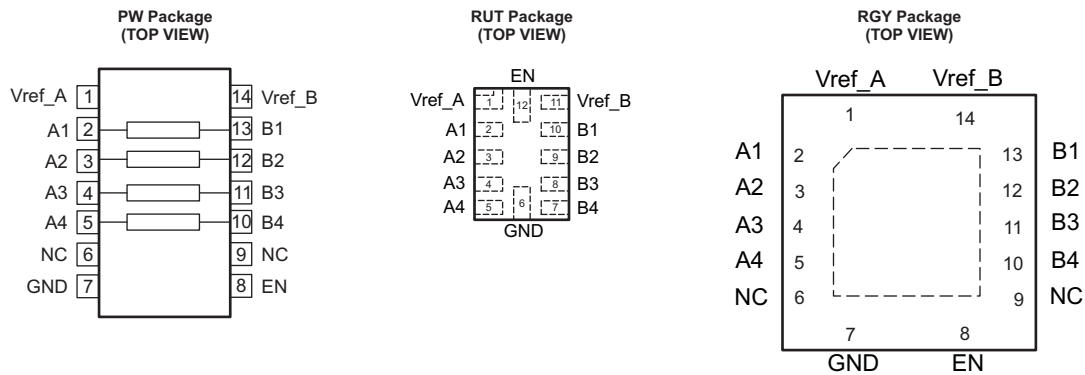
The supply voltage ($V_{pu\#}$) for each channel can be individually set up with a pull up resistor. For example, CH1 can be used in up-translation mode ($1.2\text{ V} \leftrightarrow 3.3\text{ V}$) and CH2 in down-translation mode ($2.5\text{ V} \leftrightarrow 1.8\text{ V}$).

When EN is HIGH, the translator switch is on, and the An I/O is connected to the Bn I/O, respectively, allowing bidirectional data flow between ports. When EN is LOW, the translator switch is off, and a high-impedance state exists between ports. The EN input circuit is designed to be supplied by Vref_A. To ensure the high-impedance state during power-up or power-down, EN must be LOW.

6 Device Comparison Table

PART NUMBER	EN	An	Bn	DESCRIPTION
LSF0204D	H	Place all data pins in 3 state mode (Hi-Z)	Place all data pins in 3 state mode (Hi-Z)	3-state output mode enable (active Low; referenced to Vref_A)
LSF0204D	L	Input or output	Input or output	
LSF0204	H	Input or output	Input or output	3-state output mode enable (active High, referenced to Vref_A)
LSF0204	L	Place all data pins in 3 state mode (Hi-Z)	Place all data pins in 3 state mode (Hi-Z)	

7 Pin Configuration and Functions



Pin Functions

PIN	DESCRIPTION
An/Bn	Data Port
EN	Switch enable input; LSF0204: EN is high-active LSF0204D: EN is low-active
Vref_A	Reference supply voltage; see Application and Implementation section
Vref_B	Reference supply voltage; see Application and Implementation section.

8 Specifications

8.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

		MIN	MAX	UNIT
V _I	Input voltage range ⁽²⁾	–0.5	7	V
V _{I/O}	Input/output voltage range ⁽²⁾	–0.5	7	V
	Continuous channel current		128	mA
I _{IK}	Input clamp current	VI < 0	–50	mA
T _{stg}	Storage temperature range	–65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input and input/output negative-voltage ratings may be exceeded if the input and input/output clamp-current ratings are observed.

8.2 ESD Ratings

		VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000
		Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1000

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 500-V HBM is possible with the necessary precautions.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 250-V CDM is possible with the necessary precautions.

8.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V _{I/O}	Input/output voltage	0	5	V
V _{ref_A/B/EN}	Reference voltage	0	5	V
I _{PASS}	Pass transistor current		64	mA
T _A	Operating free-air temperature	–40	125	°C

8.4 Thermal Information

THERMAL METRIC ⁽¹⁾		LSF0204			UNIT
		RGY (14 Pins)	RUT (12 Pins)	PW (14 Pins)	
R _{θJA}	Junction-to-ambient thermal resistance	83.2	195.8	157.9	°C
R _{θJC(top)}	Junction-to-case (top) thermal resistance	98.2	98.7	82.3	
R _{θJB}	Junction-to-board thermal resistance	59.2	122.6	100.0	
Ψ _{JT}	Junction-to-top characterization parameter	17.4	6.2	22.9	
Ψ _{JB}	Junction-to-board characterization parameter	59.4	122.6	99.0	
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	38.7	N/A	N/A	

- (1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

8.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		MIN	TYP ⁽¹⁾	MAX	UNIT
V_{IK}	$I_I = -18$ mA,	$V_{EN} = 0$			-1.2	V
I_{IH}	$V_I = 5$ V	$V_{EN} = 0$			5.0	μ A
I_{CCBA}	Leakage from V_{ref_B} to V_{ref_A}	$V_{ref_B} = 3.3$ V, $V_{ref_A} = 1.8$ V, $V_{EN} = V_{ref_A}$ $I_O = 0$, $V_I = 3.3$ V or GND			3.5	μ A
$I_{CCA} + I_{CCB}$ ⁽²⁾	Total Current through GND	$V_{ref_B} = 3.3$ V, $V_{ref_A} = 1.8$ V, $V_{EN} = V_{ref_A}$ $I_O = 0$, $V_I = 3.3$ V or GND		0.2		μ A
I_{IN}	Control pin current	$V_{ref_B} = 5.5$ V, $V_{ref_A} = 4.5$ V, $V_{EN} = 0$ to V_{ref_A} $I_O = 0$			± 1	μ A
I_{off}	Power Off Leakage Current	$V_{ref_B} = V_{ref_A} = 0$ V, $V_{EN} = GND$ $I_O = 0$, $V_I = 5$ V or GND			± 1	μ A
$C_{I(ref_A/B/EN)}$	$V_I = 3$ V or 0			7		pF
$C_{io(off)}$	$V_O = 3$ V or 0, $V_{EN} = 0$			5.0	6.0	pF
$C_{io(on)}$	$V_O = 3$ V or 0, $V_{EN} = V_{ref_A}$			10.5	13	pF
V_{IH} (EN pin)	High-level input voltage ⁽³⁾	$V_{ref_A} = 1.5$ V to 4.5 V	$0.7 \times V_{ref_A}$			V
V_{IL} (EN pin)	Low-level input voltage	$V_{ref_A} = 1.5$ V to 4.5 V		$0.3 \times V_{ref_A}$		V
V_{IH} (EN pin)	High-level input voltage	$V_{ref_A} = 1.0$ V to 1.5 V	$0.8 \times V_{ref_A}$			V
V_{IL} (EN pin)	Low-level input voltage	$V_{ref_A} = 1.0$ V to 1.5 V		$0.3 \times V_{ref_A}$		V
$\Delta t/\Delta v$ (EN pin)	Input transition rise or fall rate for EN pin			10		ns/V
r_{on} ⁽⁴⁾	$V_I = 0$, $I_O = 64$ mA	$V_{ref_A} = V_{EN} = 3.3$ V; $V_{ref_B} = 5$ V		3		Ω
		$V_{ref_A} = V_{EN} = 1.8$ V; $V_{ref_B} = 5$ V		4		
	$V_I = 0$, $I_O = 32$ mA	$V_{ref_A} = V_{EN} = 1.0$ V; $V_{ref_B} = 5$ V		9		Ω
		$V_{ref_A} = V_{EN} = 1.8$ V; $V_{ref_B} = 5$ V		4		
	$V_I = 0$, $I_O = 32$ mA	$V_{ref_A} = V_{EN} = 2.5$ V; $V_{ref_B} = 5$ V		10		Ω
	$V_I = 1.8$ V, $I_O = 15$ mA	$V_{ref_A} = V_{EN} = 3.3$ V; $V_{ref_B} = 5$ V		5		Ω
	$V_I = 1.0$ V, $I_O = 10$ mA	$V_{ref_A} = V_{EN} = 1.8$ V; $V_{ref_B} = 3.3$ V		8		Ω
	$V_I = 0$ V, $I_O = 10$ mA	$V_{ref_A} = V_{EN} = 1.0$ V; $V_{ref_B} = 3.3$ V		6		Ω
	$V_I = 0$ V, $I_O = 10$ mA	$V_{ref_A} = V_{EN} = 1.0$ V; $V_{ref_B} = 1.8$ V		6		Ω

(1) All typical values are at $T_A = 25^\circ\text{C}$.

(2) The actual supply current for LSF0204 is $I_{CCA} + I_{CCB}$; the leakage from V_{ref_B} to V_{ref_A} can be measured on V_{ref_A} and V_{ref_B} pin

(3) Enable pin test conditions are for the LSF0204. The enable pin test conditions for LSF0204D are oppositely set.

(4) Measured by the voltage drop between the A and B terminals at the indicated current through the switch. On-state resistance is determined by the lowest voltage of the two (A or B) terminals.

8.6 Switching Characteristics: AC Performance (Translating Down, 3.3 V to 1.8 V)

over recommended operating free-air temperature range, $V_{rev-A} = 1.8$ V, $V_{rev-B} = 3.3$ V, $V_{EN} = 1.8$ V, $V_{pu_1} = 3.3$ V, $V_{pu_2} = 1.8$ V, $R_L = NA$, $V_{IH} = 3.3$ V, $V_{IL} = 0$ V, $V_M = 1.15$ V (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$C_L = 50$ pF		$C_L = 30$ pF		$C_L = 15$ pF		UNIT
			TYP	MAX	TYP	MAX	TYP	MAX	
t_{PLH}	A or B	B or A	0.7	5.49	0.5	5.29	0.3	5.19	ns
t_{PHL}			0.9	4.9	0.7	4.7	0.5	4.5	ns
t_{PLZ}			13	18	12	16.5	11	15	ns
t_{PZL}			33	45	30	40	23	37	ns
f_{MAX}			50		100		100		MHz

8.7 Switching Characteristics: AC Performance (Translating Down, 3.3 V to 1.2 V)

over recommended operating free-air temperature range $V_{\text{rev-A}} = 1.2 \text{ V}$, $V_{\text{rev-B}} = 3.3 \text{ V}$, $V_{\text{EN}} = 1.2 \text{ V}$, $V_{\text{pu}_1} = 3.3 \text{ V}$, $V_{\text{pu}_2} = 1.2 \text{ V}$, $R_L = \text{NA}$, $V_{\text{IH}} = 3.3 \text{ V}$, $V_{\text{IL}} = 0 \text{ V}$, $V_M = 0.85 \text{ V}$ (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$C_L = 50 \text{ pF}$		$C_L = 30 \text{ pF}$		$C_L = 15 \text{ pF}$		UNIT
			TYP	MAX	TYP	MAX	TYP	MAX	
t_{PLH}	A or B	B or A	0.8	4.1	0.5	3.9	0.3	3.8	ns
t_{PHL}			0.9	4.7	0.7	4.5	0.6	4.3	ns
f_{MAX}			50		100		100		MHz

8.8 Switching Characteristics: AC Performance (Translating Up, 1.8 V to 3.3 V)

over recommended operating free-air temperature range $V_{\text{rev-A}} = 1.8 \text{ V}$, $V_{\text{rev-B}} = 3.3 \text{ V}$, $V_{\text{EN}} = 1.8 \text{ V}$, $V_{\text{pu}_1} = 3.3 \text{ V}$, $V_{\text{pu}_2} = 1.8 \text{ V}$, $R_L = 500 \Omega$, $V_{\text{IH}} = 1.8 \text{ V}$, $V_{\text{IL}} = 0 \text{ V}$, $V_M = 0.9 \text{ V}$ (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$C_L = 50 \text{ pF}$		$C_L = 30 \text{ pF}$		$C_L = 15 \text{ pF}$		UNIT
			TYP	MAX	TYP	MAX	TYP	MAX	
t_{PLH}	A or B	B or A	0.6	5.7	0.4	5.3	0.2	5.13	ns
t_{PHL}			1.3	6.7	1	6.4	0.7	5.3	ns
t_{PLZ}			13	18	12	16.5	11	15	ns
t_{PZL}			33	45	30	40	23	37	ns
f_{MAX}			50		100		100		MHz

8.9 Switching Characteristics: AC Performance (Translating Up, 1.2 V to 1.8 V)

over recommended operating free-air temperature range, $V_{\text{rev-A}} = 1.2 \text{ V}$, $V_{\text{rev-B}} = 1.8 \text{ V}$, $V_{\text{EN}} = 1.2 \text{ V}$, $V_{\text{pu}_1} = 1.8 \text{ V}$, $V_{\text{pu}_2} = 1.2 \text{ V}$, $R_L = 500 \Omega$, $V_{\text{IH}} = 1.2 \text{ V}$, $V_{\text{IL}} = 0 \text{ V}$, $V_M = 0.6 \text{ V}$ (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$C_L = 50 \text{ pF}$		$C_L = 30 \text{ pF}$		$C_L = 15 \text{ pF}$		UNIT
			TYP	MAX	TYP	MAX	TYP	MAX	
t_{PLH}	A or B	B or A	0.65	7.25	0.4	7.05	0.2	6.85	ns
t_{PHL}			1.6	7.03	1.3	6.5	1	5.4	ns
f_{MAX}			50		100		100		MHz

8.10 Typical Characteristics

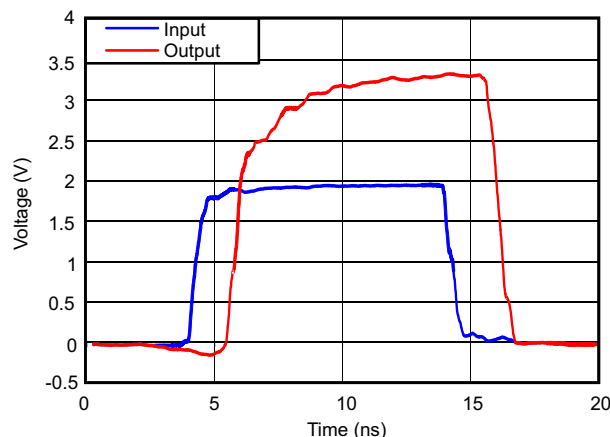
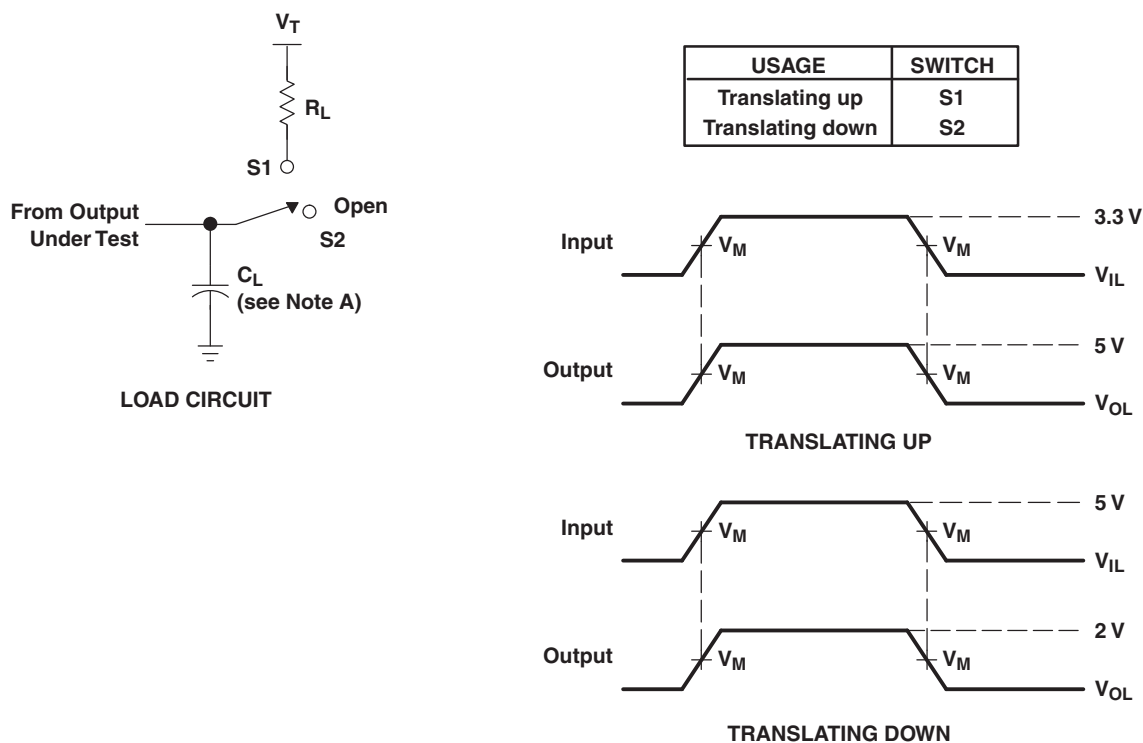


Figure 1. Signal Integrity (1.8 V to 3.3 V Translation Up at 50 MHz)

9 Parameter Measurement Information



NOTES: A. C_L includes probe and jig capacitance.

B. All input pulses are supplied by generators having the following characteristics: $PRR \leq 10$ MHz, $Z_O = 50 \Omega$, $t_r \leq 2$ ns, $t_f \leq 2$ ns.

C. The outputs are measured one at a time, with one transition per measurement.

Figure 2. Load Circuit for Outputs

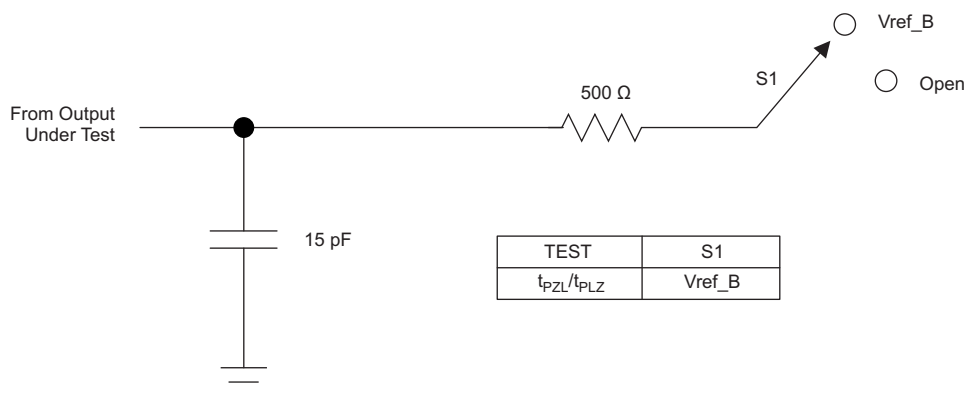


Figure 3. Load Circuit for Enable/Disable Time Measurement

9.1 Load Circuit AC Waveform for Outputs

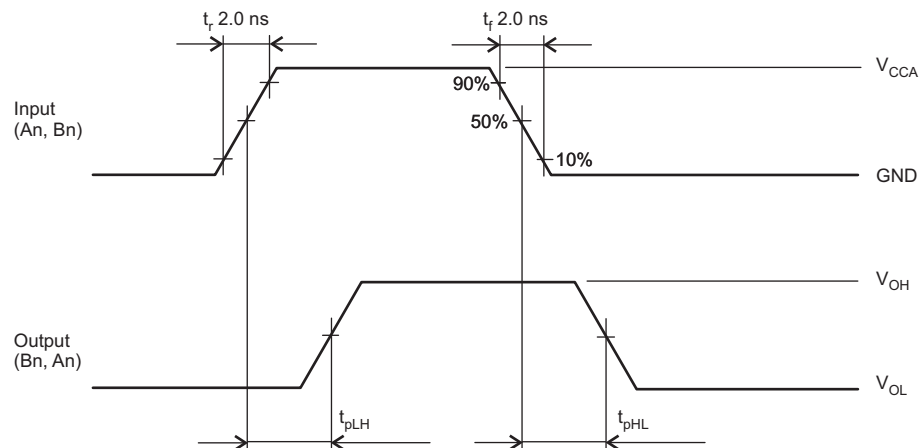


Figure 4. t_{PLH} , t_{PHL}

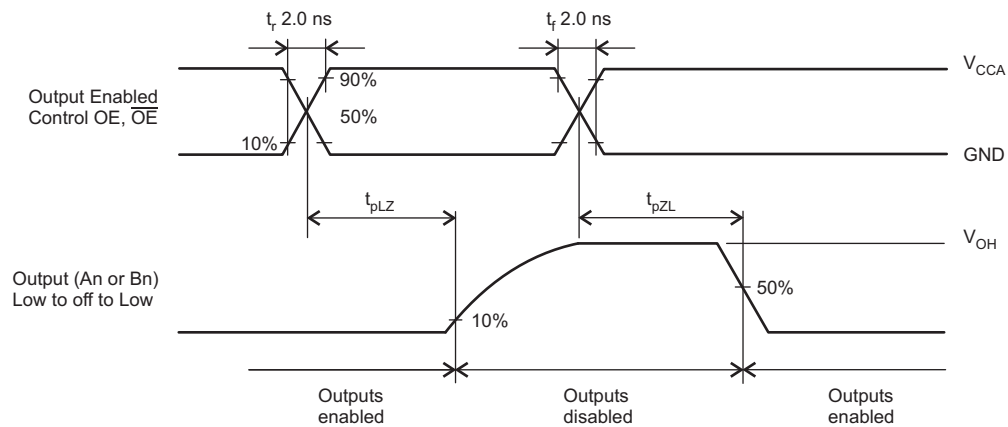


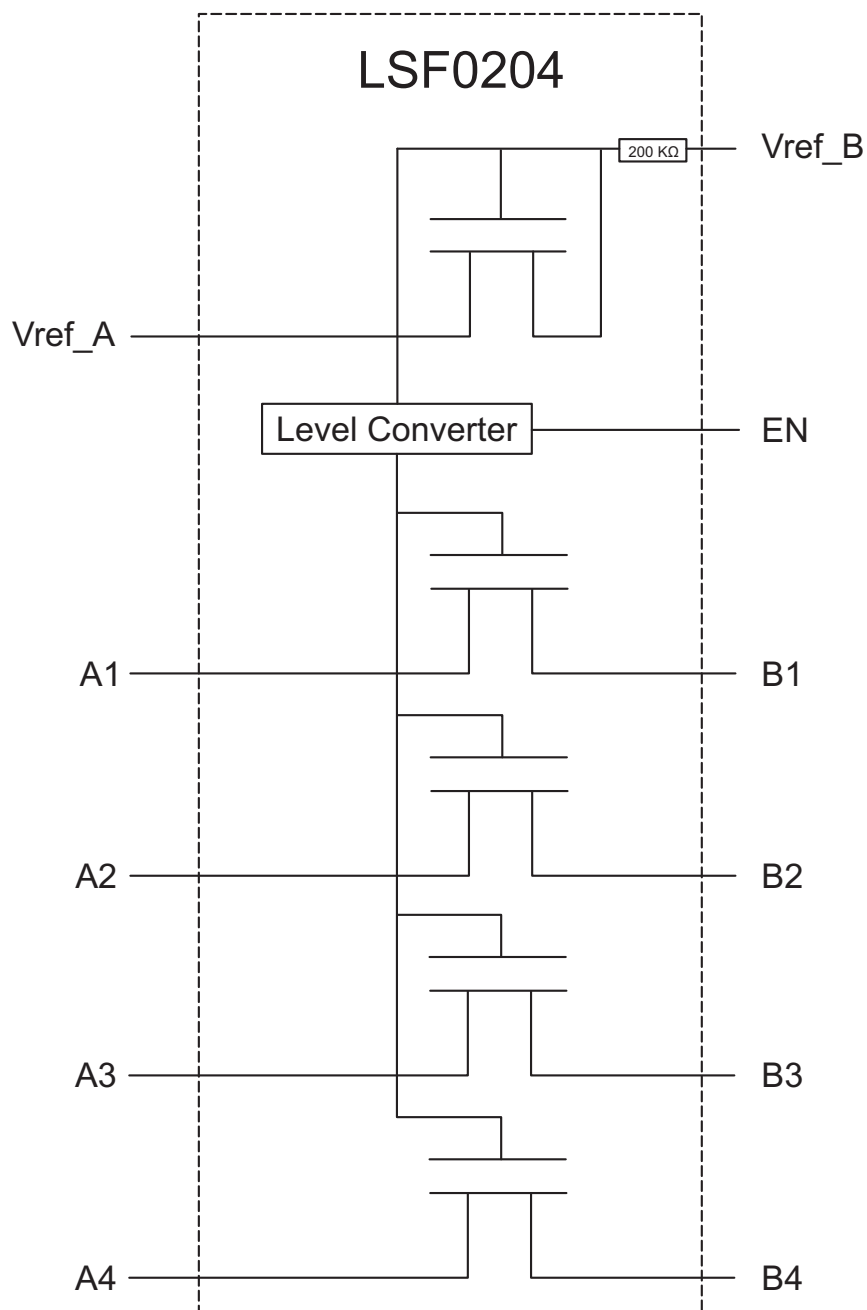
Figure 5. t_{PLZ} , t_{PZL}

10 Detailed Description

10.1 Overview

The LSF Family can be used in level translation applications for interfacing devices or systems operating at different interface voltages with one another. The LSF Family is ideal for use in applications where an open-drain driver is connected to the data I/Os. With appropriate pull-up resistors and layout, LSF can achieve 100 MHz. The LSF Family can also be used in applications where a push-pull driver is connected to the data I/Os.

10.2 Functional Block Diagram



10.3 Feature Description

10.3.1 Support High Speed Translation, Greater than 100 MHz

Allows the LSF family to support more consumer or telecom interfaces (MDIO or SDIO).

10.3.2 Bidirectional Voltage Translation Without DIR Terminal

Minimizes system effort to develop voltage translation for bidirectional interface (PMBus, I2C, or SMBus).

10.3.3 5V Tolerance on IO Port and 125°C Support

With 5 V tolerance and 125°C support, the LSF family is flexible and compliant with TTL levels in industrial and telecom applications.

10.3.4 Channel Specific Translation

The LSF family is able to set up different voltage translation levels on each channel.

10.3.5 Ioff, Partial Power Down Mode

When V_{ref_A} , $V_{ref_B} = 0$, all of data pins and EN pin are Hi-Z.

Since EN logic circuit is supplied by V_{ref_A} , once V_{ref_A} power up first, all of data pins are unknown state until V_{ref_B} and EN ready. No power sequence requirement to enable LSF0204 and operate function normally.

10.4 Device Functional Modes

Function Table

INPUT EN ⁽¹⁾ TERMINAL	FUNCTION
H	$A_n = B_n$
L	Hi-Z

(1) EN is controlled by V_{ref_A} logic levels.

11 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

11.1 Application Information

LSF is able to perform voltage translation for open-drain or push-pull interface. Table 1 provides some consumer/telecom interfaces as reference in regards to the different channel numbers that are supported by the LSF family.

Table 1. Voltage Translator for Consumer/Telecom Interface

PART NAME	CH#	INTERFACE
LSF0101	1	GPIO
LSF0102	2	GPIO, MDIO, SMBus, PMBus, I2C
LSF0204	4	SPI, MDIO, SMBus, PMBus, I2C, UART, SVID
LSF0108	8	GPIO, MDIO, SDIO, SVID, UART, SMBus, PMBus, I2C, SPI

11.2 I2C PMBus, SMBus, GPIO, Application

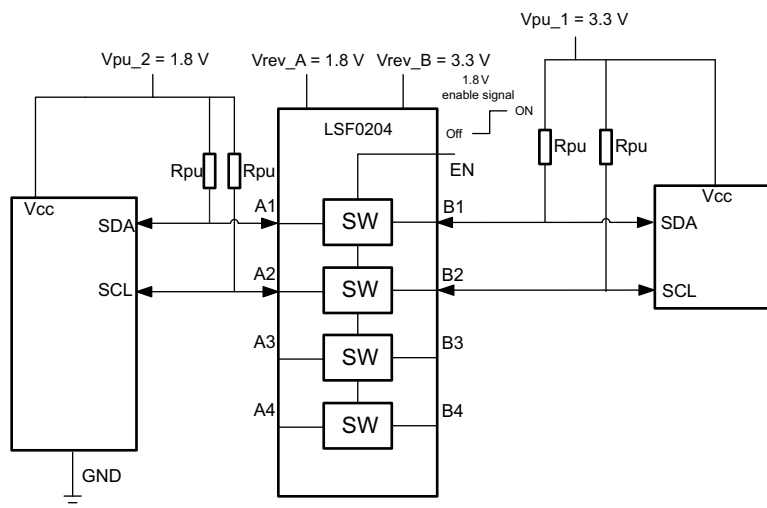


Figure 6. Bidirectional Translation to Multiple Voltage Levels

11.2.1 Design Requirements

11.2.1.1 Enable, Disable, and Reference Voltage Guidelines

The LSF family has an EN input that is used to disable the device by setting EN LOW, which places all I/Os in the high-impedance state. Since LSF family is switch-type voltage translator, the power consumption is very low. It is recommended to always enable LSF family for bidirectional application (I2C, SMBus, PMBus, or MDIO).

I2C PMBus, SMBus, GPIO, Application (continued)
Table 2. Application Operating Condition

SYMBOL	PARAMETER	MIN	TYP	MAX	UNIT
Vref_A	Reference voltage (A)	1		4.5	V
Vref_B	Reference voltage (B)	Vref_A + 0.8		5.5	V
V _{I(EN)} ⁽¹⁾	Input voltage on EN terminal	0		Vref_A	V
Vpu	Pull-up supply voltage	0		Vref_B	V

(1) Refer V_{IH} and V_{IL} for V_{I(EN)}

Also Vref_B is recommended to be at 1.0 V higher than Vref_A for best signal integrity.

LSF Family is able to set different voltage translation level on each channel

NOTE

Vref_A must be set as lowest voltage level.

11.2.2 Detailed Design Procedure
11.2.2.1 Bidirectional Translation

The master output driver can be push-pull or open-drain (pull-up resistors may be required) and the slave device output can be push-pull or open-drain (pull-up resistors are required to pull the Bn outputs to Vpu).

However, if either output is push-pull, data must be unidirectional or the outputs must be 3-state and be controlled by some direction-control mechanism to prevent HIGH-to-LOW contentions in either direction. If both outputs are open-drain, no direction control is needed.

In [Figure 6](#), the reference supply voltage (Vref_A) is connected to the processor core power supply voltage. When Vref_B is connected through to a 3.3 V Vpu power supply, and Vref_A is set 1.0V. The output of A3 and B4 has a maximum output voltage equal to Vref_A, and the bidirectional interface (Ch1/2, MDIO) has a maximum output voltage equal to Vpu.

11.2.2.1.1 Pull-up Resistor Sizing

The pull-up resistor value needs to limit the current through the pass transistor when it is in the ON state to about 15 mA. This ensures a pass voltage of 260 mV to 350 mV. If the current through the pass transistor is higher than 15 mA, the pass voltage also is higher in the ON state. To set the current through each pass transistor at 15 mA, to calculate the pull-up resistor value use [Equation 1](#).

$$R_{pu} = (V_{pu} - 0.35 \text{ V}) / 0.015 \text{ A} \quad (1)$$

[Table 3](#) summarizes resistor values, reference voltages, and currents at 15 mA, 10 mA, and 3 mA. The resistor value shown in the +10% column (or a larger value) should be used to ensure that the pass voltage of the transistor is 350 mV or less. The external driver must be able to sink the total current from the resistors on both sides of the LSF family device at 0.175 V, although the 15 mA applies only to current flowing through the LSF family device.

Table 3. Pull-up Resistor Values⁽¹⁾⁽²⁾

V_{DPU}	PULL-UP RESISTOR VALUE (Ω)					
	15 mA	10 mA	3 mA			
	NOMINAL	+10% ⁽³⁾	NOMINAL	+10% ⁽³⁾	NOMINAL	+10% ⁽³⁾
5 V	310	341	465	512	1550	1705
3.3 V	197	217	295	325	983	1082
2.5 V	143	158	215	237	717	788
1.8 V	97	106	145	160	483	532
1.5 V	77	85	115	127	383	422
1.2 V	57	63	85	94	283	312

(1) Calculated for $V_{OL} = 0.35$ V

(2) Assumes output driver $V_{OL} = 0.175$ V at stated current

(3) +10% to compensate for V_{DD} range and resistor tolerance

11.2.2.2 LS Family Bandwidth

The maximum frequency of the LSF family is dependent on the application. The device can operate at speeds of >100MHz given the correct conditions. The maximum frequency is dependent upon the loading of the application. The LSF family behaves like a standard switch where the bandwidth of the device is dictated by the on resistance and on capacitance of the device.

Figure 7 shows a bandwidth measurement of the LSF family using a two-port network analyzer.

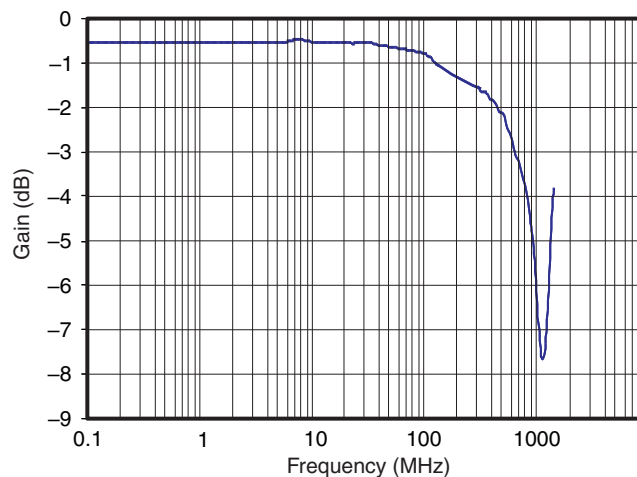


Figure 7. 3-dB Bandwidth

The 3-dB point of the LSF family is ≈ 600 MHz; however, this measurement is an analog type of measurement. For digital applications the signal should not degrade up to the fifth harmonic of the digital signal. The frequency bandwidth should be at least five times the maximum digital clock rate. This component of the signal is very important in determining the overall shape of the digital signal. In the case of the LSF family, a digital clock frequency of greater than 100 MHz can be achieved.

The LSF family does not provide any drive capability. Therefore higher frequency applications will require higher drive strength from the host side. No pull-up resistor is needed on the host side (3.3 V) if the LSF family is being driven by standard CMOS totem pole output driver. Ideally, it is best to minimize the trace length from the LSF family on the sink side (1.8 V) to minimize signal degradation.

All fast edges have an infinite spectrum of frequency components; however, there is an inflection (or "knee") in the frequency spectrum of fast edges where frequency components higher than f_{knee} are insignificant in determining the shape of the signal.

To calculate the maximum "practical" frequency component, or the "knee" frequency (f_{knee}), use the following equations:

$$f_{\text{knee}} = 0.5/RT \text{ (10–80\%)} \quad (2)$$

$$f_{\text{knee}} = 0.4/RT \text{ (20–80\%)} \quad (3)$$

For signals with rise time characteristics based on 10- to 90-percent thresholds, f_{knee} is equal to 0.5 divided by the rise time of the signal. For signals with rise time characteristics based on 20% to 80% thresholds, which is very common in many of today's device specifications, f_{knee} is equal to 0.4 divided by the rise time of the signal.

Some guidelines to follow that will help maximize the performance of the device:

- Keep trace length to a minimum by placing the LSF family close to the I²C output of the processor.
- The trace length should be less than half the time of flight to reduce ringing and line reflections or non-monotonic behavior in the switching region.
- To reduce overshoots, a pull-up resistor can be added on the 1.8 V side; be aware that a slower fall time is to be expected.

11.2.3 Application Curve

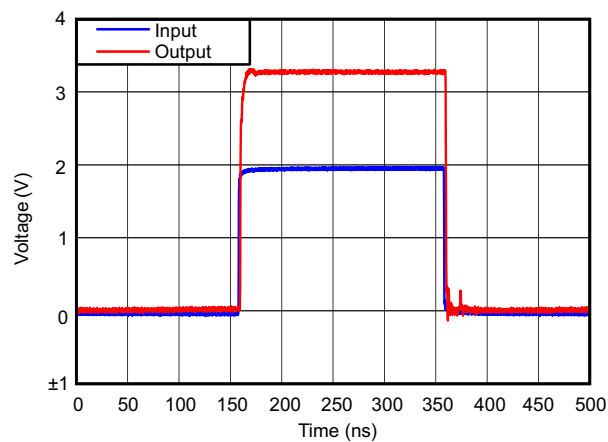


Figure 8. Captured Waveform From Above I²C Set-Up (1.8 to 3.3 V at 2.5 MHz)

11.2.4 MDIO Application

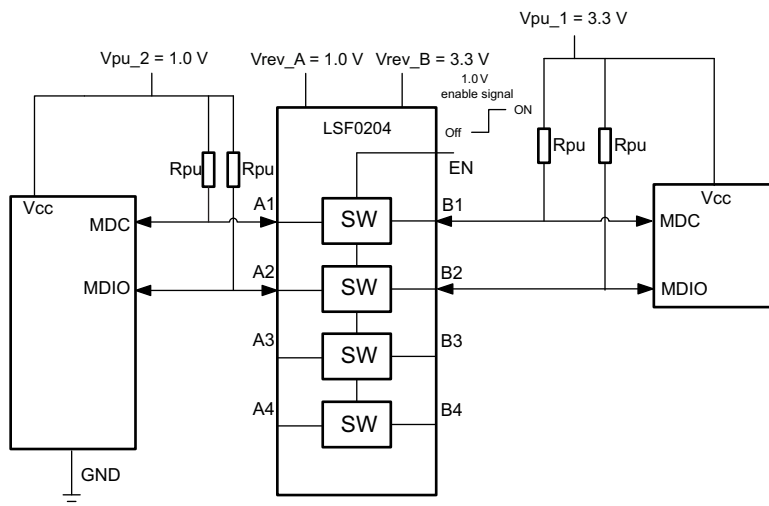


Figure 9. Typical Application Circuit (MDIO/Bidirectional Interface)

11.2.4.1 Design Requirements

Refer to [Design Requirements](#).

11.2.4.2 Detailed Design Procedure

Refer to [Detailed Design Procedure](#)

11.2.4.3 Application Curve

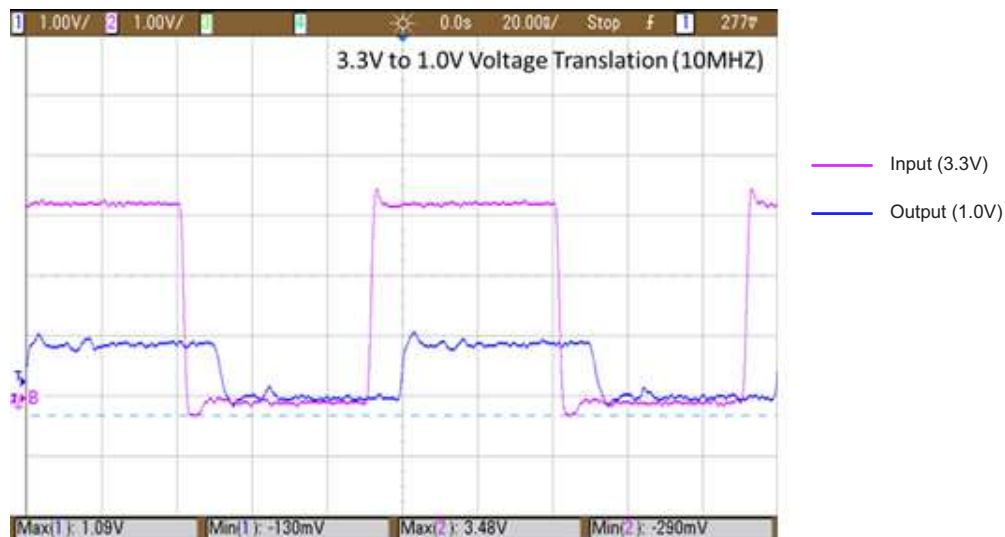
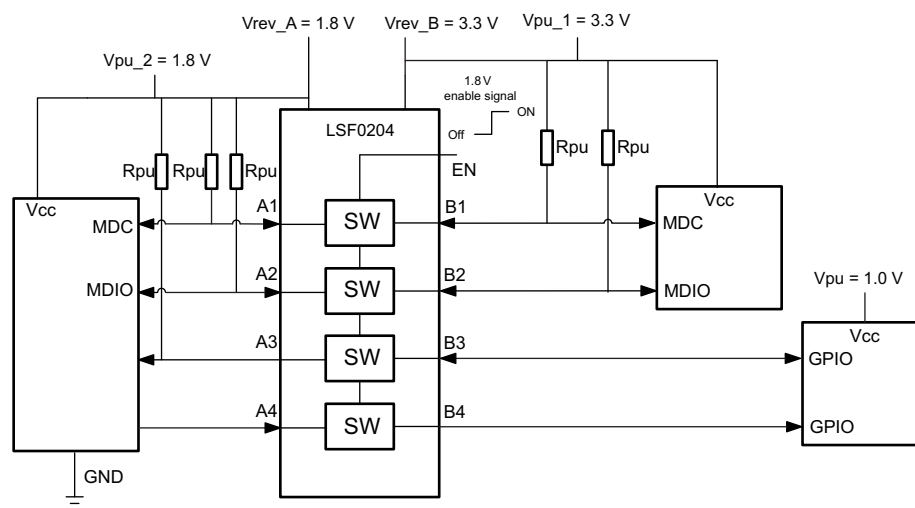


Figure 10. Captured Waveform From Above MDIO Setup

11.2.5 Multiple Voltage Translation in Single Device, Application



11.2.5.1 Design Requirements

Refer to [Design Requirements](#).

11.2.5.2 Detailed Design Procedure

Refer to [Detailed Design Procedure](#)

11.2.5.3 Application Curves

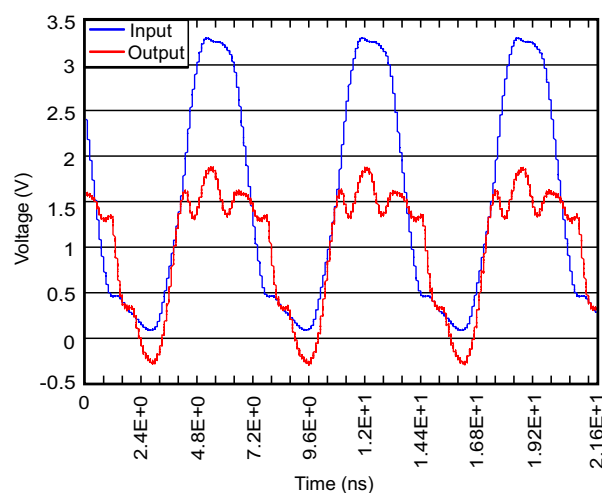


Figure 11. Translation Down (3.3 to 1.8 V) at 150 MHz

12 Power Supply Recommendations

There are no power sequence requirements for the LSF Family. For enable and reference voltage guidelines, refer to the [Enable, Disable, and Reference Voltage Guidelines](#).

13 Layout

13.1 Layout Guidelines

Since LSF Family is switch-type level translator, the signal integrity is highly related with pull-up resistor and PCB capacitance condition.

- Short signal trace as possible to reduce capacitance and minimize stub from pull-up resistor.
- Place LSF close to high voltage side.
- Select the appropriate pull-up resistor that applies to translation levels and driving capability of transmitter.

13.2 Layout Example

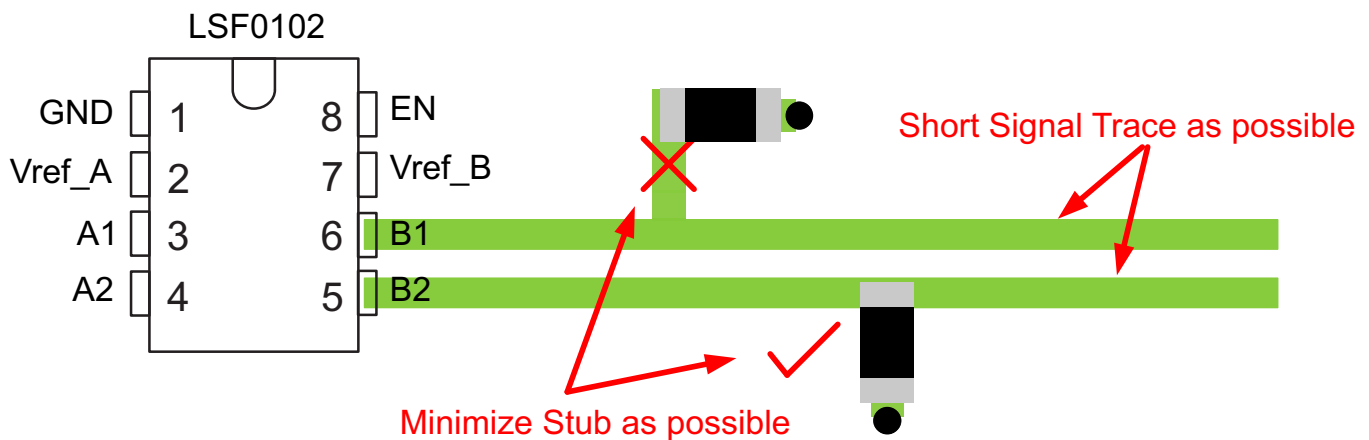


Figure 12. Short Trace Layout

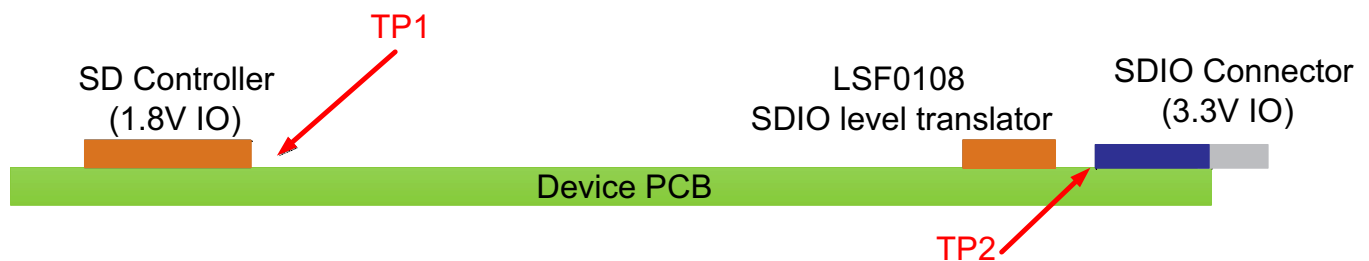


Figure 13. Device Placement

Layout Example (接下页)

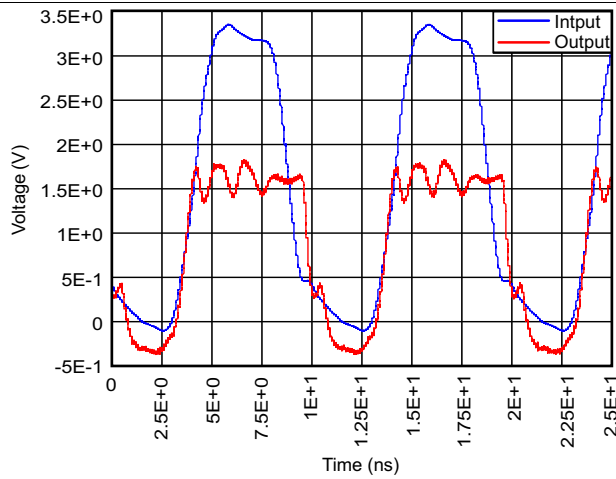


Figure 14. Waveform From TP1 (Pullup Resistor: 160 Ω and 50-pF Capacitance 3.3 to 1.8 V at 100 MHz)

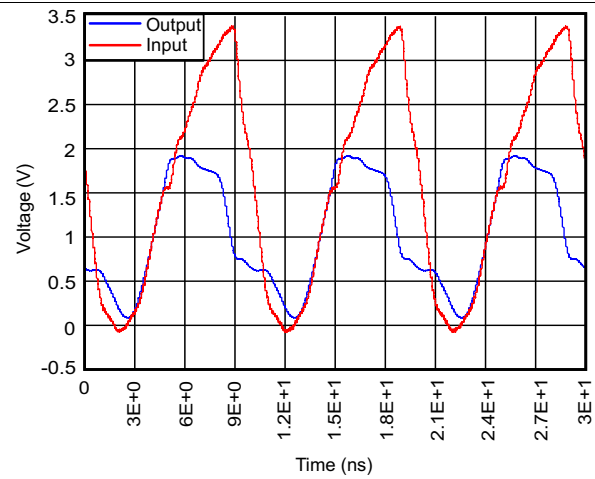


Figure 15. Waveform From TP2 (Pullup Resistor: 160 Ω and 50-pF Capacitance 1.8 to 3.3 V at 100 MHz)

14 器件和文档支持

14.1 相关链接

以下表格列出了快速访问链接。范围包括技术文档、支持与社区资源、工具和软件，并且可以快速访问样片或购买链接。

表 4. 相关链接

器件	产品文件夹	样片与购买	技术文档	工具与软件	支持与社区
LSF0204	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处
LSF0204D	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处

14.2 商标

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14.3 静电放电警告



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14.4 术语表

[SLYZ022](#) — TI 术语表。

这份术语表列出并解释术语、首字母缩略词和定义。

15 机械封装和可订购信息

以下页中包括机械封装和可订购信息。 这些信息是针对指定器件可提供的最新数据。 这些数据会在无通知且不对本文档进行修订的情况下发生改变。 欲获得该数据表的浏览器版本，请查阅左侧的导航栏。

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LSF0204DPWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	LSF204D	Samples
LSF0204DRGYR	ACTIVE	VQFN	RGY	14	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	LSF24D	Samples
LSF0204DRUTR	ACTIVE	UQFN	RUT	12	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	SIO	Samples
LSF0204DYZPR	ACTIVE	DSBGA	YZP	12	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 125	G6	Samples
LSF0204PWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	LSF204	Samples
LSF0204RGYR	ACTIVE	VQFN	RGY	14	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	LSF24	Samples
LSF0204RUTR	ACTIVE	UQFN	RUT	12	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	SIN	Samples
LSF0204YZPR	ACTIVE	DSBGA	YZP	12	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 125	G5	Samples

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Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LSF0204DPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
LSF0204DRGYR	VQFN	RGY	14	3000	330.0	12.4	3.75	3.75	1.15	8.0	12.0	Q1
LSF0204DRUTR	UQFN	RUT	12	3000	180.0	9.5	1.9	2.3	0.75	4.0	8.0	Q1
LSF0204DYZPR	DSBGA	YZP	12	3000	180.0	8.4	1.63	2.08	0.69	4.0	8.0	Q2
LSF0204PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
LSF0204RGYR	VQFN	RGY	14	3000	330.0	12.4	3.75	3.75	1.15	8.0	12.0	Q1
LSF0204RUTR	UQFN	RUT	12	3000	180.0	9.5	1.9	2.3	0.75	4.0	8.0	Q1
LSF0204YZPR	DSBGA	YZP	12	3000	180.0	8.4	1.63	2.08	0.69	4.0	8.0	Q2

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LSF0204DPWR	TSSOP	PW	14	2000	364.0	364.0	27.0
LSF0204DRGYR	VQFN	RGY	14	3000	367.0	367.0	35.0
LSF0204DRUTR	UQFN	RUT	12	3000	184.0	184.0	19.0
LSF0204DYZPR	DSBGA	YZP	12	3000	182.0	182.0	20.0
LSF0204PWR	TSSOP	PW	14	2000	364.0	364.0	27.0
LSF0204RGYR	VQFN	RGY	14	3000	367.0	367.0	35.0
LSF0204RUTR	UQFN	RUT	12	3000	184.0	184.0	19.0
LSF0204YZPR	DSBGA	YZP	12	3000	182.0	182.0	20.0

PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



4040064-3/G 02/11

- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
 - E. Falls within JEDEC MO-153

PW (R-PDSO-G14)

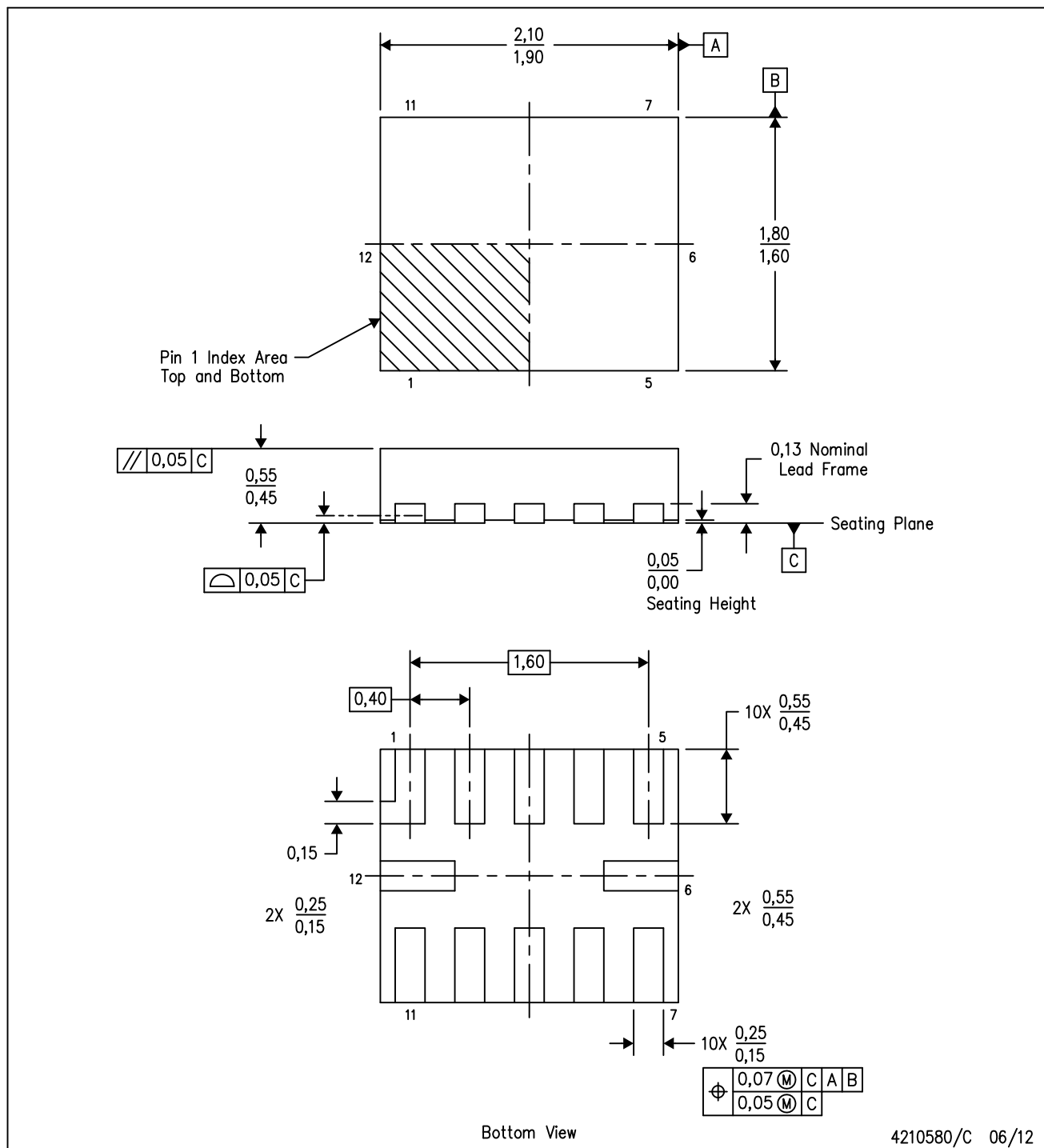
PLASTIC SMALL OUTLINE



- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Publication IPC-7351 is recommended for alternate designs.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

RUT (R-PUQFN-N12)

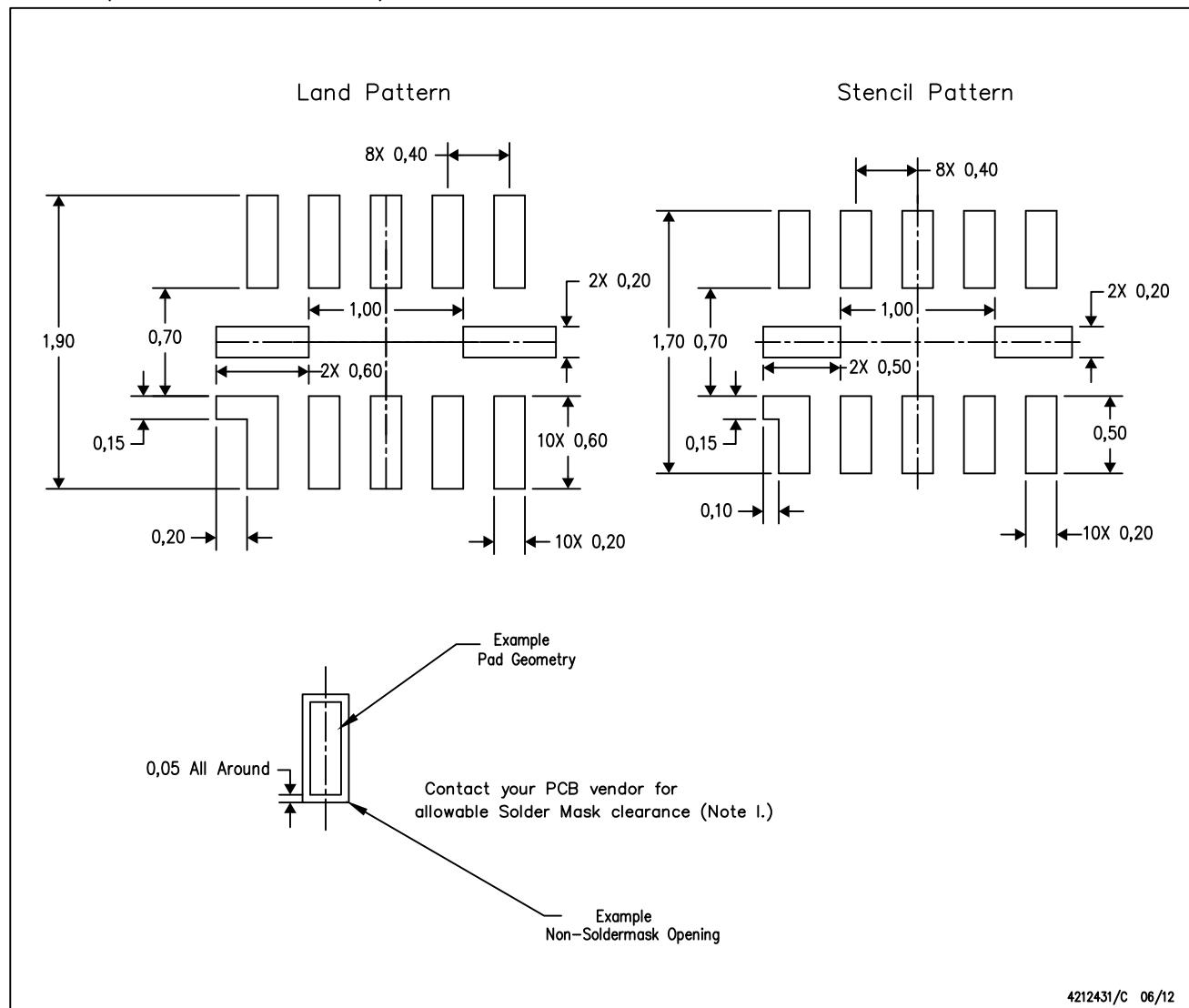
PLASTIC QUAD FLATPACK NO-LEAD



- NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
B. This drawing is subject to change without notice.
C. QFN (Quad Flatpack No-Lead) package configuration.

RUT (R-PUQFN-N12)

PLASTIC QUAD FLATPACK NO-LEAD

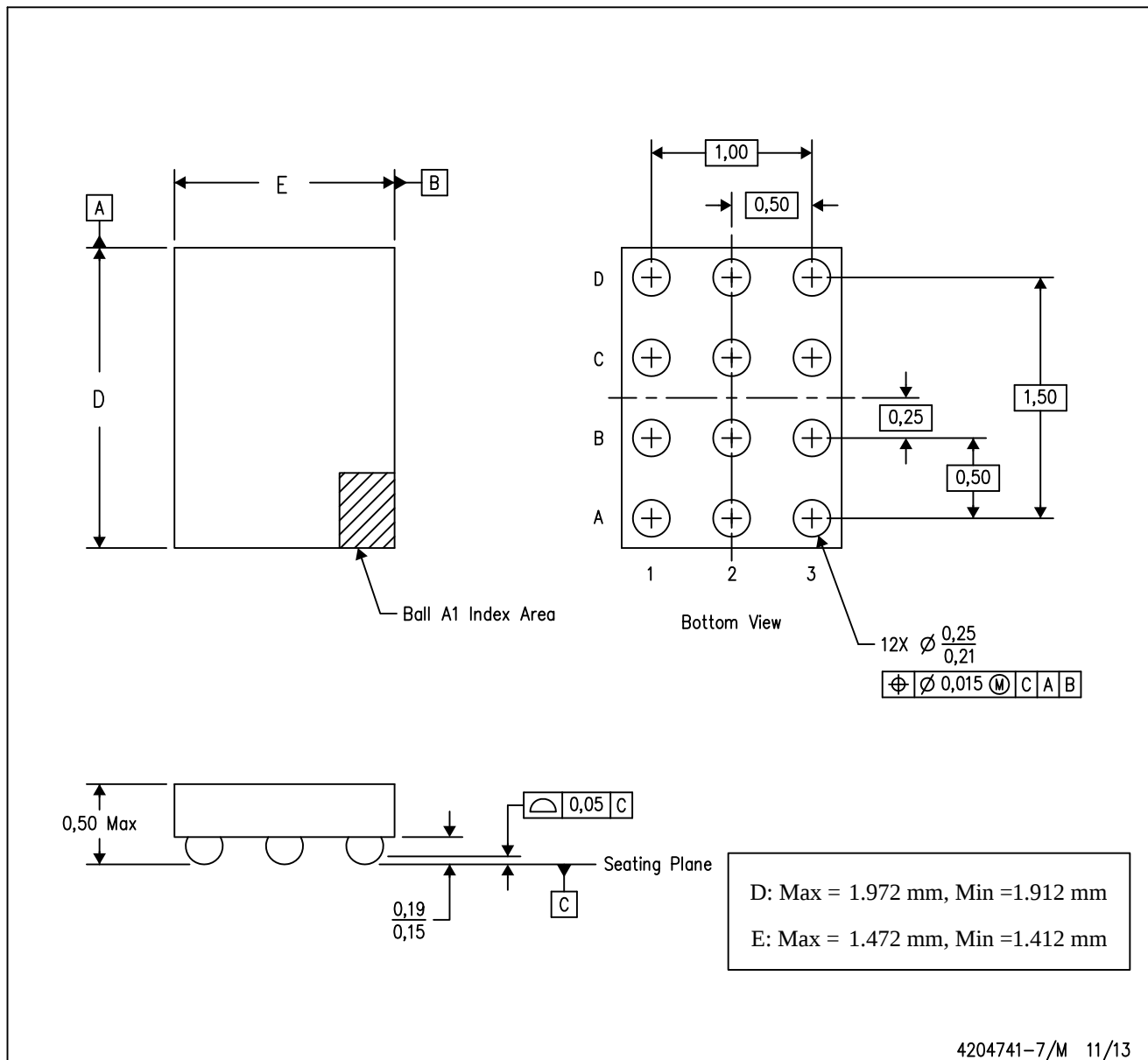


4212431/C 06/12

- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.
 - E. Maximum stencil thickness 0,1016 mm (4 mils). All linear dimensions are in millimeters.
 - F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
 - G. Over-printing land for larger area ratio is not advised due to land width and bridging potential. Exercise extreme caution.
 - H. Suggest stencils cut with lasers such as Fiber Laser that produce the greatest positional accuracy.
 - I. Component placement force should be minimized to prevent excessive paste block deformation.

YZP (R-XBGA-N12)

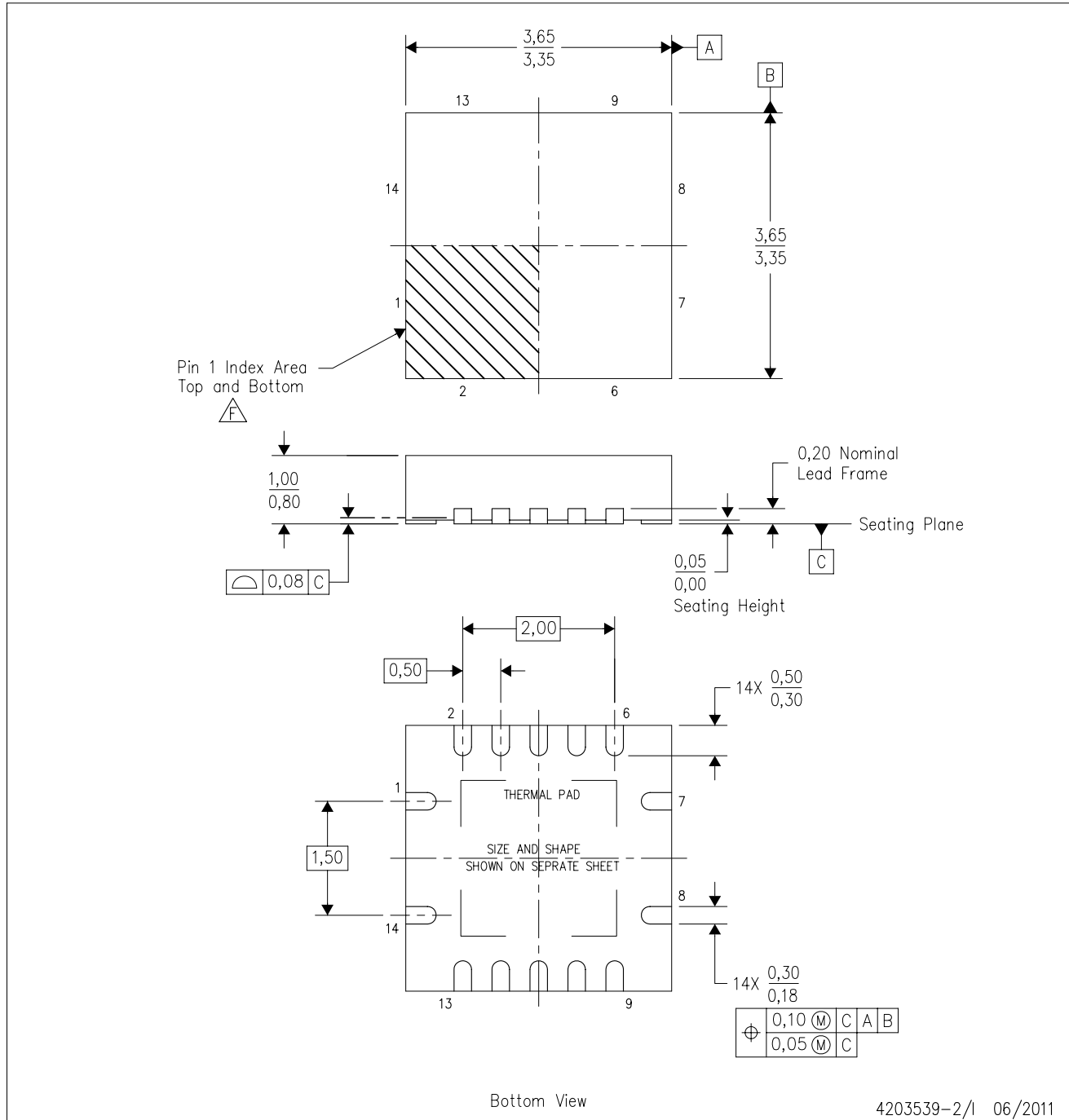
DIE-SIZE BALL GRID ARRAY



- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. NanoFree™ package configuration.

RGY (S-PVQFN-N14)

PLASTIC QUAD FLATPACK NO-LEAD



4203539-2/I 06/2011

- NOTES:
- All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - This drawing is subject to change without notice.
 - QFN (Quad Flatpack No-Lead) package configuration.
 - The package thermal pad must be soldered to the board for thermal and mechanical performance.
 - See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
 - Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
 - Package complies to JEDEC MO-241 variation BA.

RGY (S-PVQFN-N14)

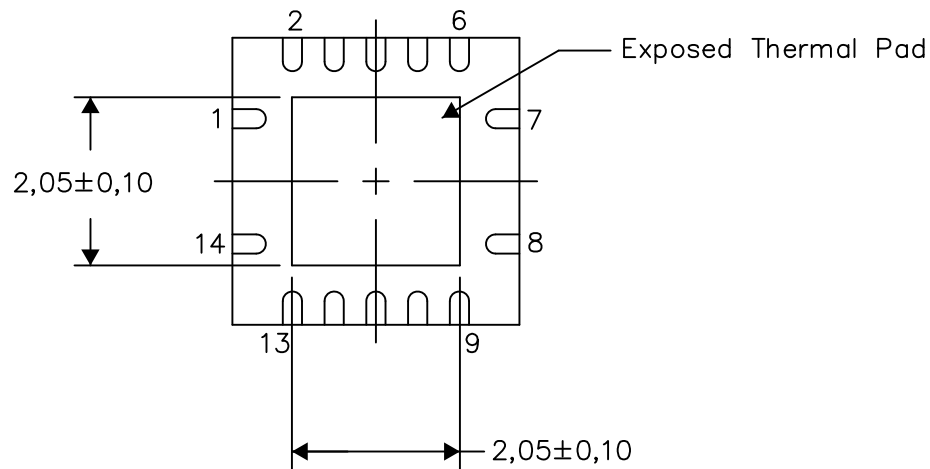
PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

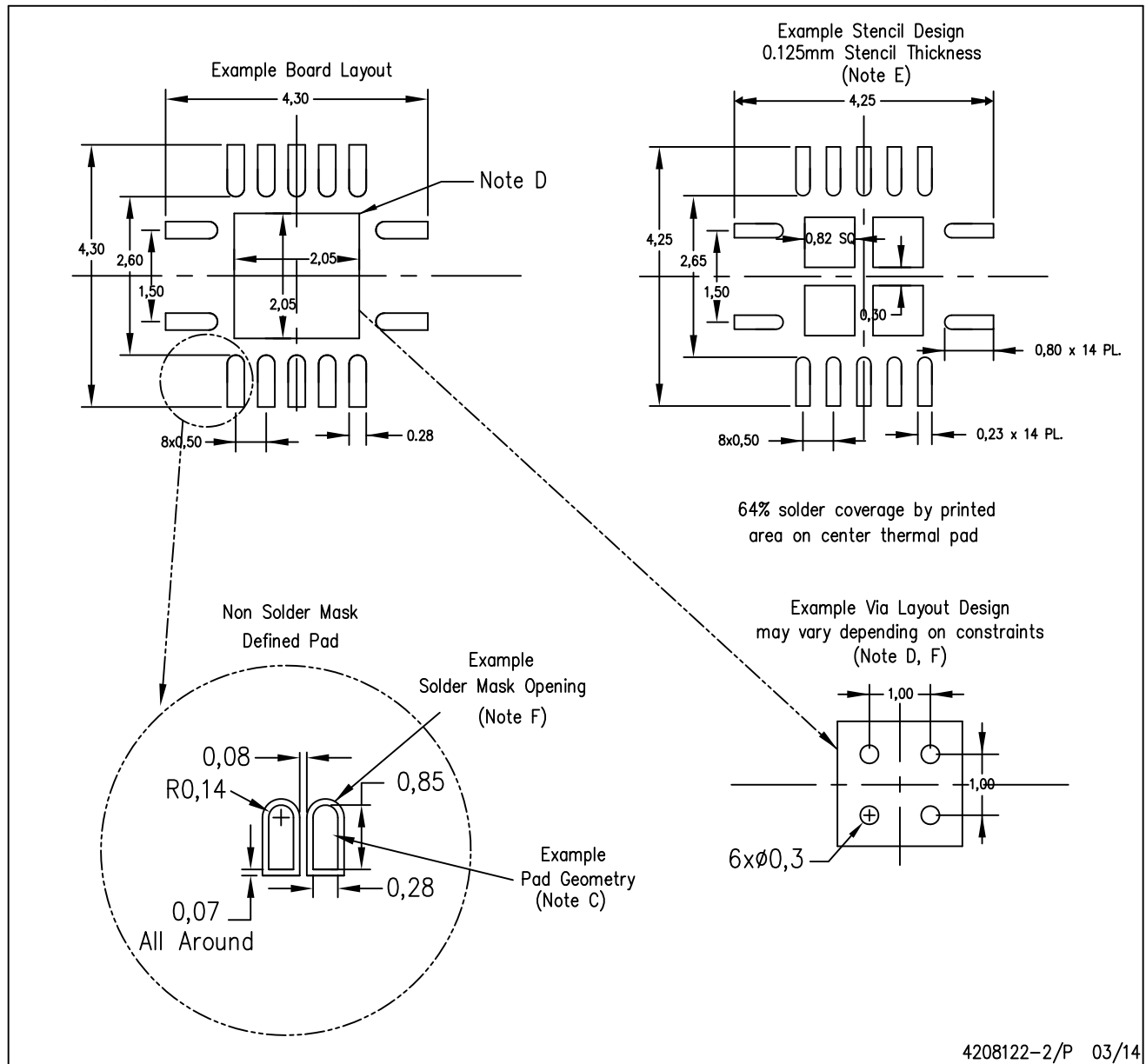
Exposed Thermal Pad Dimensions

4206353-2/P 03/14

NOTE: All linear dimensions are in millimeters

RGY (S-PVQFN-N14)

PLASTIC QUAD FLATPACK NO-LEAD



4208122-2/P 03/14

- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <<http://www.ti.com>>.
 - E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
 - F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.

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